



<b>Form 1449 (Modified)</b>  <b>Information Disclosure Statement By Applicant</b>  (Use Several Sheets if Necessary)	Atty Docket No. UNTYP015 Applicant: Rinerson et al. Filing Date July 1, 2003	Application No.: 10/612,733  Group <del>2818</del> 2824
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**U.S. Patent Documents**

Examiner Initial	No.	Patent No.	Date	Patentee	Class	Sub-class	Filing Date
gu	A	6,204,139	2001-03-20	Liu et al.			
	B	5,920,500	1999-07-06	Tehrani et al.			
	C	6,545,891	2003-04-08	Tringali et al.			
	D	6,504,753	2003-01-07	Scheuerlein et al.			
	E	6,483,736	2002-11-19	Johnson et al.			
	F	6,385,074	2002-05-07	Johnson et al.			
	G	6,351,406	2002-02-26	Johnson et al.			
	H	6,185,122	2001-02-06	Johnson et al.			
	I	6,034,882	2000-03-07	Johnson et al.			
	J	5,835,396	1998-11-10	Zhang			
gu	K	4,442,507	1994-04-10	Roesner			

**U.S. Published Patent Applications**

Examiner Initial	No.	Document No.	Publication Date	Inventor
gu	J	2002/0000597 A1	01/03/02	Okazawa
gu	K	2001/0023992 A1	09/27/01	Doll

**Other Documents**

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication
gu	L	Beck, A. et al., "Reproducible switching effect in thin oxide films for memory applications", Applied Physics Letters, Vol. 77, No. 1, 3 July 2000, 139-141.
gu	M	Rossel, C. et al., "Electrical current distribution across a metal-insulator-metal structure during bistable switching", Journal of Applied Physics, Vol. 90, No. 6, 15 September 2001, 2892-2898.
gu	N	Watanabe, Y. et al., "Current-driven insulator-conductor transition and nonvolatile memory in chromium-doped SrTiO <sub>3</sub> single crystals", Applied Physics Letters, Vol. 78, No. 23, 4 June 2001, 3738-3740.
Examiner <u>Vu le</u>		Date Considered <u>8/30/05</u>

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



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**Other Documents**

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication
ju	A	Liu, S.Q., et al., "Electric-pulse-induced reversible resistance change effect in magnetoresistive films", Applied Physics Letters, Vol. 76, No. 19, 8 May 2000, 2749-2651.
ju	B	Liu, S.Q., et al., "A New Concept For Non-Volatile Memory: Electric-Pulse Induced Reversible Resistance Change Effect In Magnetoresistive Films", Space Vacuum Epitaxy Center, University of Huston, Huston TX, 7 Pages.
Examiner	Vu le	Date Considered 8/30/05

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